

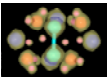
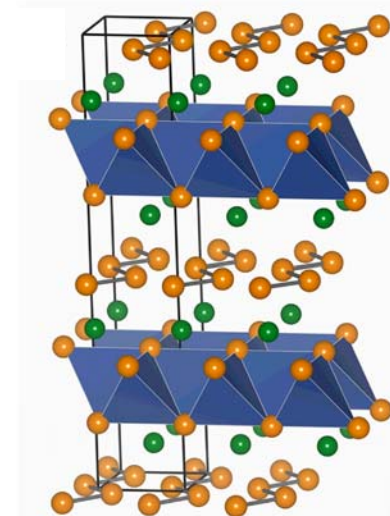
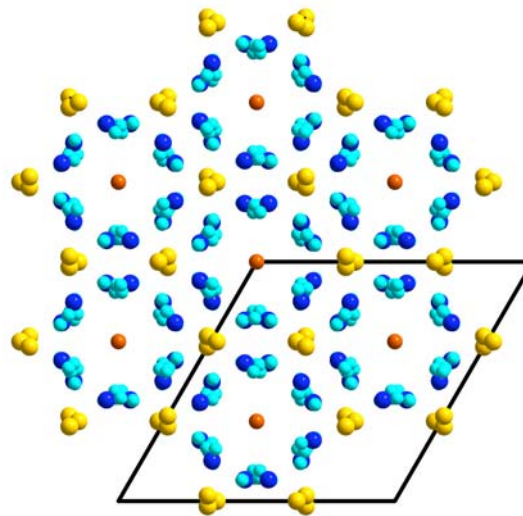
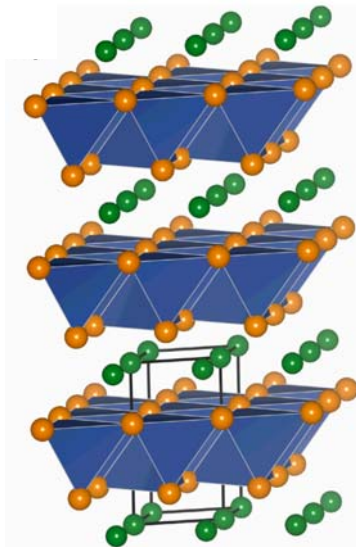


Low-Cost and Non-Toxic Zn-Sb Zintl Compounds for Thermoelectrics

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<http://thermoelectrics.caltech.edu>



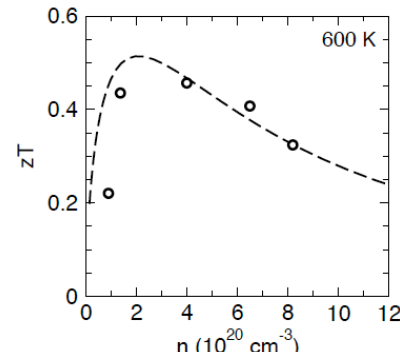
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Snyder et. al. *Nature Materials*, 7, p. 105, (2008)

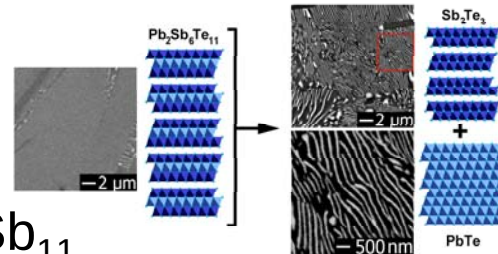
Caltech Thermoelectrics



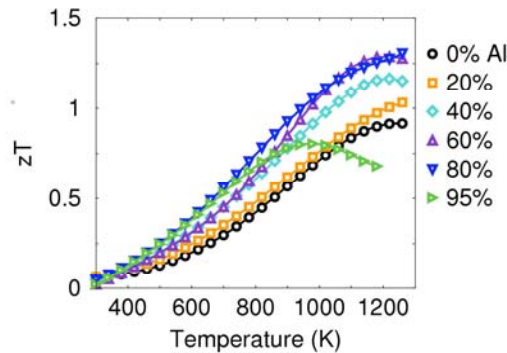
2009 Group BBQ



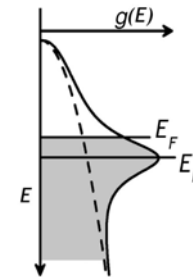
Clathrates



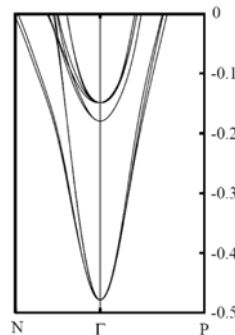
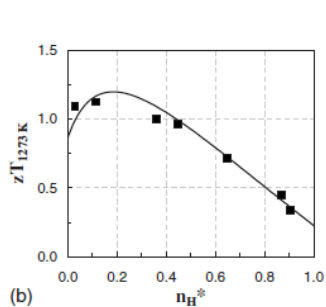
Nanostructures



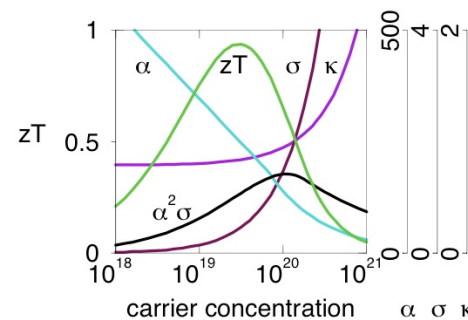
$\text{Yb}_{14}\text{MnSb}_{11}$
Zintl compounds



PbTe:TI
Resonant states



La_3Te_4



Review Articles



Zinc and Antimony



Low Cost

Iron < \$1/kg

Zinc \$2/kg

Silicon \$2/kg

Aluminum \$2/kg

Lead \$2/kg

Magnesium \$3/kg

Ca, Sr, Ba < \$5/kg

Cadmium \$5/kg

Antimony \$6/kg

Copper \$6/kg

Ce, La \$8/kg

Tin \$15/kg

Cobalt \$40/kg

Selenium \$50/kg

Lithium \$70/kg

Tellurium \$140/kg

Indium \$500/kg

Gallium \$500/kg

Germanium

\$1000/kg

Non Toxic

Both elements used as flame retardants in consumer products

Antimony Oxide Sb_2O_3

Zinc Oxide Borate

$2\text{ZnO} \cdot 3\text{B}_2\text{O}_3 \cdot 3.5\text{H}_2\text{O}$

Both used as synergistic co-additives in combination with halogen compounds

most concern over polybrominated biphenyl

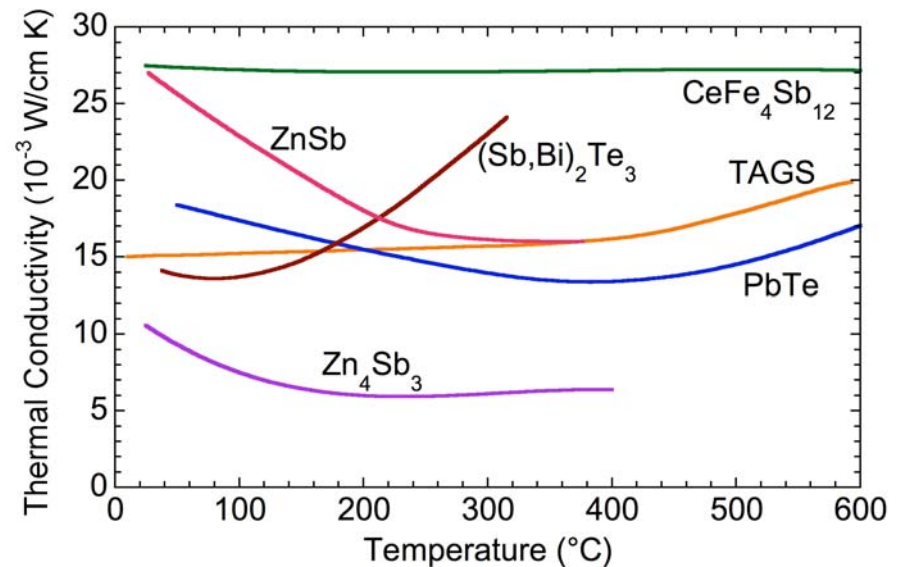
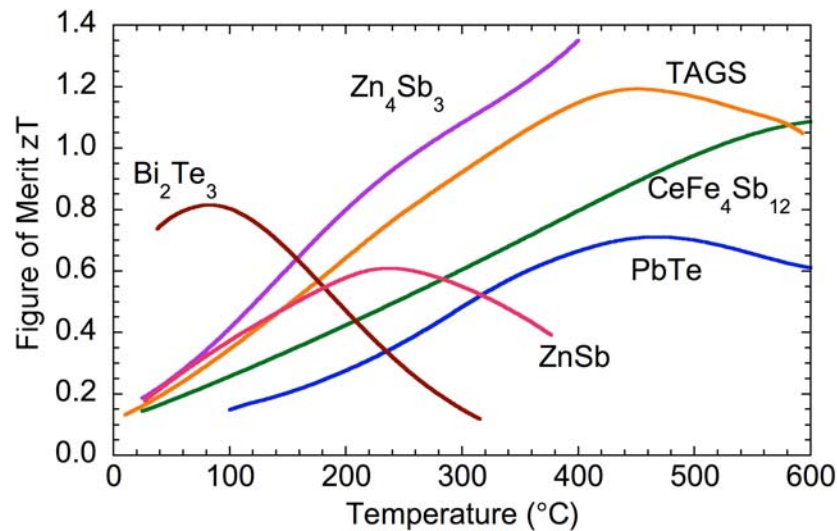
<http://www.inchem.org/documents/ehc/ehc/ehc192.htm>

High zT Zn_4Sb_3



Zn_4Sb_3
Highest TE Figure of Merit

Because of exceptionally low
thermal conductivity



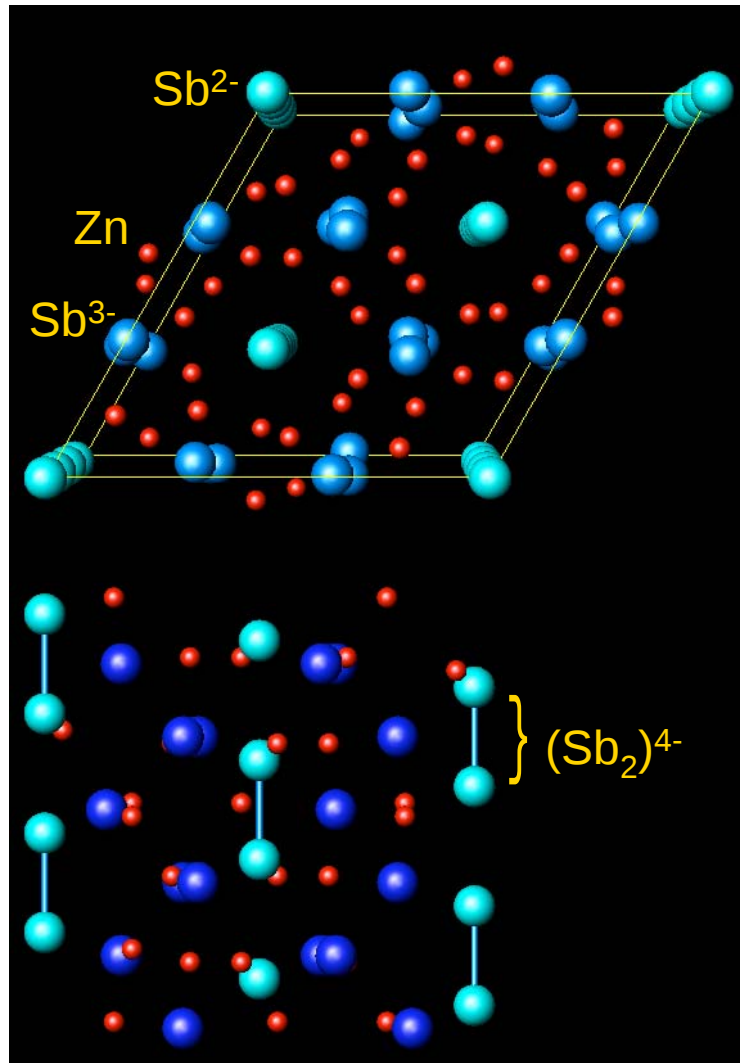
Crystal structure should explain thermal properties

complex crystal structure, disorder, grain structure, composite microstructure ?

Crystal structure should explain electronic properties

Valence compound from Zintl chemistry

Zn₄Sb₃ Core Structure



Contains two types of Sb

Single Bonded Sb²⁻ dimers (1.2/f.u.)

Isolated Sb³⁻ (1.8/f.u.)

Valence balance: Zn_{3.9}Sb₃ (Zn²⁺)

One Zn site

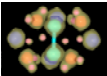
4Sb + 1Zn coordination

Will only fit Zn_{3.6}Sb₃

Where is extra Zinc?

Chemical analysis: Zn_{3.95(5)}Sb₃

p-type Semi. Con: Zn_{3.9-δ}Sb₃



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Interstitial Zn in Zn_4Sb_3



Zn interstitial sites

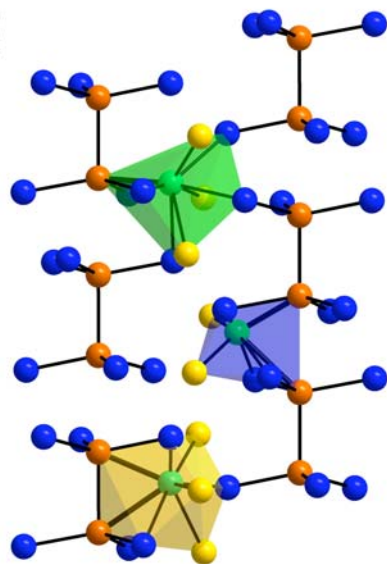
Three unequivocal regions of excess electron density in XRD

Maximum Entropy Method & Bader Topological Analysis

Coupled to vacancy on primary Zn site (10% vacancies)

20% of Zn is interstitial

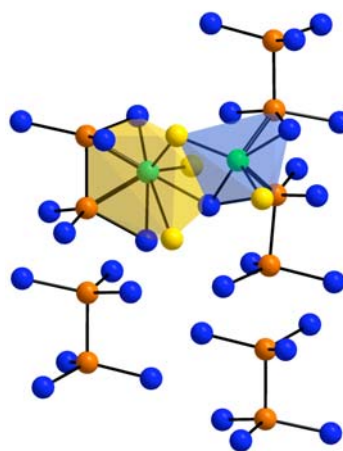
Many configurations, sites may be possible



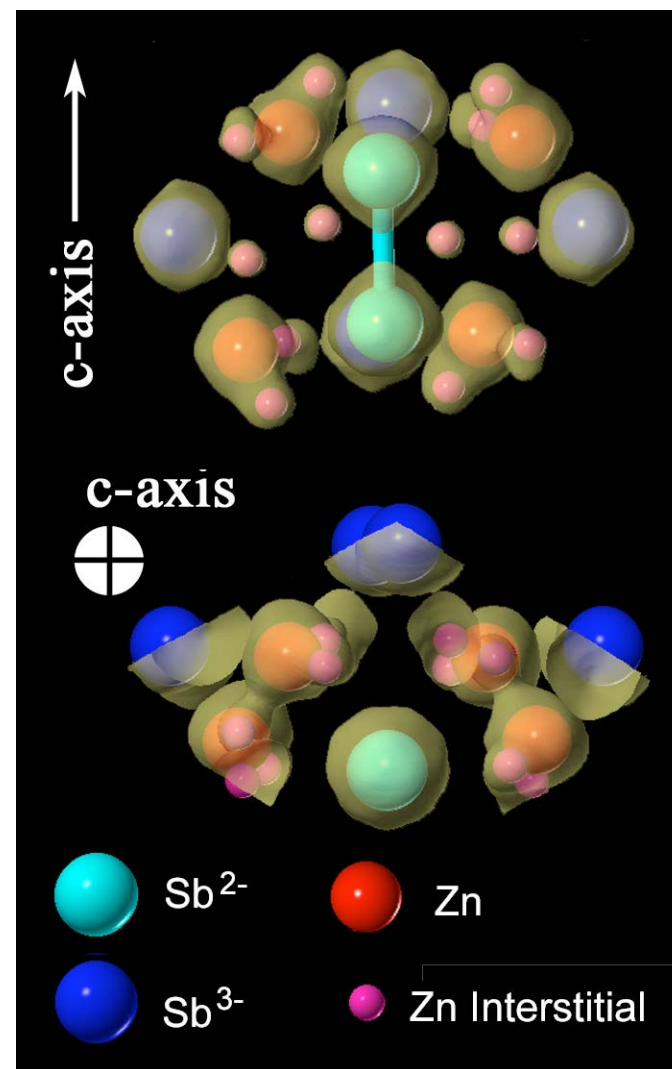
3 interstitial types (300K)

Toberer et al. *Phys. Stat. Sol.-RRL* **3**, 458 (2004)

Boström, et al. *J. Alloys Compounds*, **376**, 49 (2004)



Coupled interstitials (100K)



Snyder et al. *Nature Materials* **3**, 458 (2004)
Chem. Eur. **10** 3862 (2004)

Nanoparticles discovered in Zn_4Sb_3



10-20nm Zn particles found in Zn_4Sb_3

likely to be an additional mechanism for reduced thermal conductivity in Zn_4Sb_3

Must be due to a phase instability: likely a (coherent) solid-solid precipitation

Unknown orientation relationship of Zn particles in Zn_4Sb_3

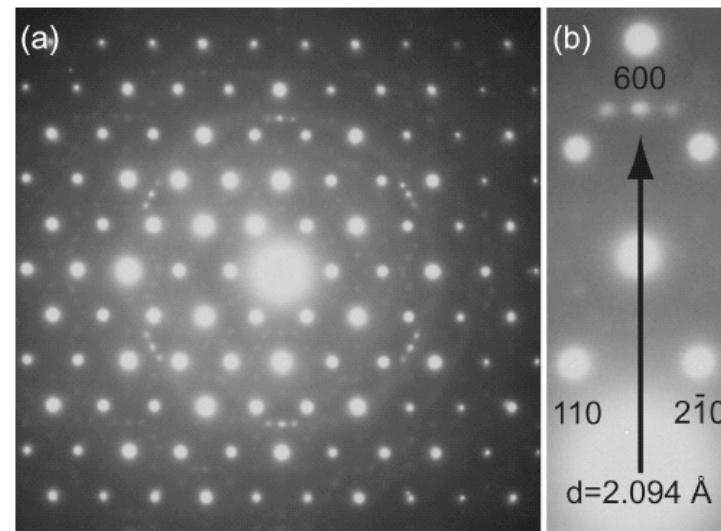
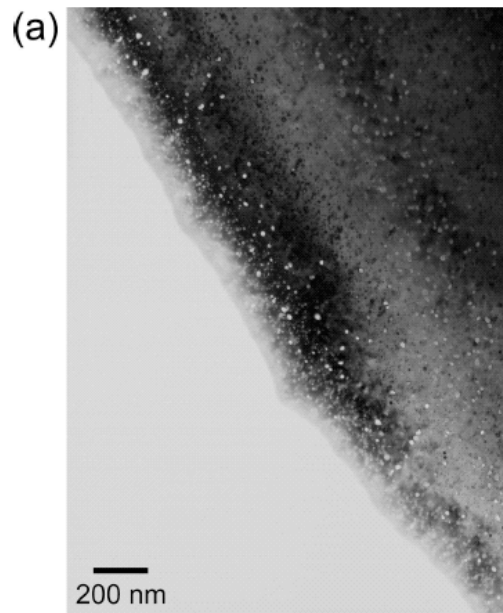
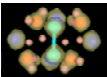


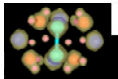
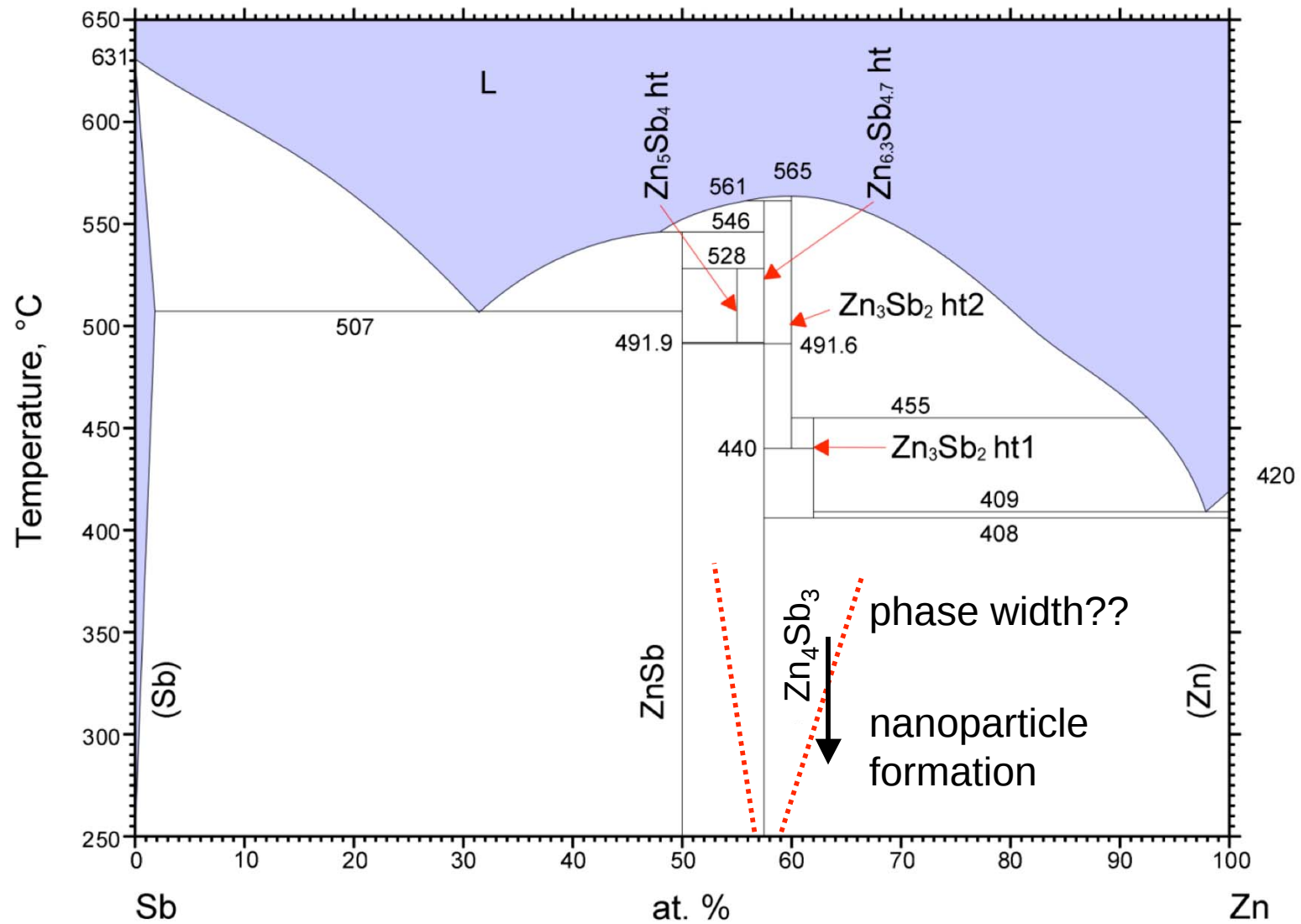
FIG. 3: (a) Selected area diffraction pattern taken with a long exposure time in the $[001]$ projection of the Zn_4Sb_3 phase.

Prytz, et al, *Philosophical Magazine Letters*, **V 89**, p362 (2009)



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Zn-Sb Phase Diagram



Lattice Thermal Conductivity in Zn_4Sb_3



Mechanisms for low κ_l in Zn_4Sb_3

1. Large Unit Cell

$\kappa_l \sim 1/\text{Primitive cell } 309 \text{ \AA}^3$

Low Temp $\alpha\text{-Zn}_4\text{Sb}_3$ cell $2135 \text{ \AA}^3$

2. local distortion microstructure ($\sim 10 \text{ \AA}$)

Kim, et al, *Phys. Rev. B*, **75**, 134103 (2007)

3. Interstitial disorder (point defect)

Toberer, *Phys. Stat. Sol.-RRL* **3**, 458 (2004)

4. Interstitial motion

liquid like diffusivity

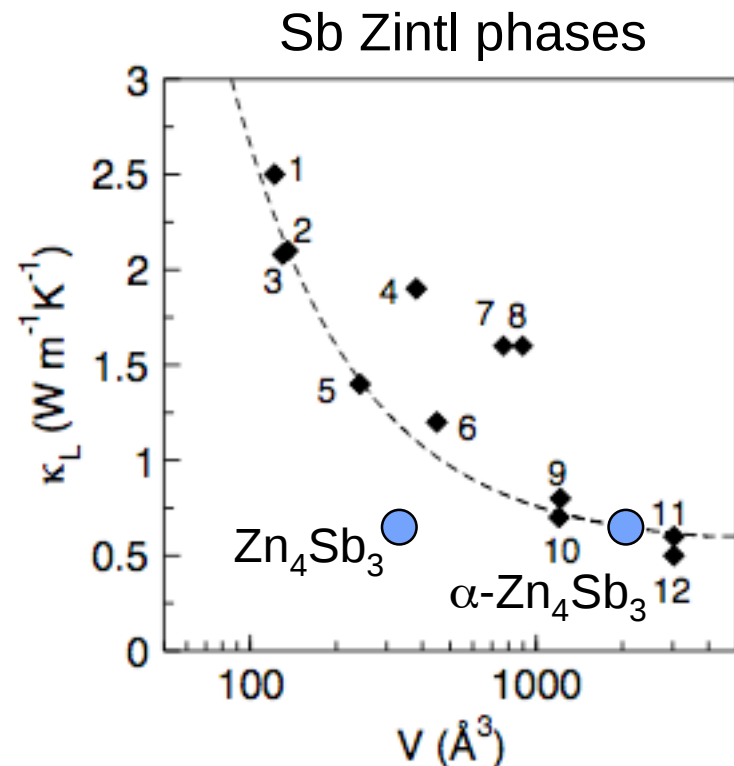
Chafin, *Sol. State Ionics*, **178**, 447 (2007)

5. Nanoparticles

Prytz, et al, *Phil. Mag. Lett.*, **89**, p362 (2009)

These also complicate stability, lifetime during use.

Require better understanding before commercialization



Substructure Approach to TE



Separate *Phonon Glass* from *Electron Crystal*

Use complexity to disrupt phonons more than electrons

- length scale: e- mean-free-path < phonon mean-free-path
- chemistry: minimize disruption of atoms contributing to bands at E_f
- physics: mass (vs. bonding) complexity has more impact on phonons than e⁻

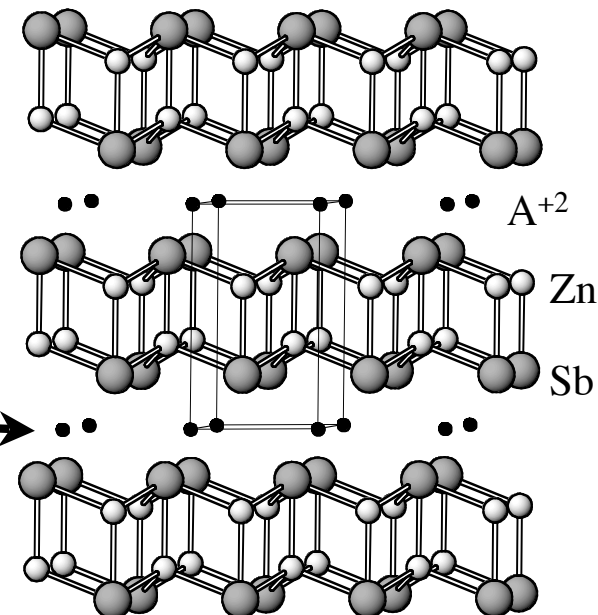
Zintl Phases

Valence Balance provides band gap

- e.g. $\text{Ca}^{+2}_x \text{Yb}^{+2}_{1-x} \text{Zn}^{+2}_2 \text{Sb}^{-3}_2$

Distinct Anionic & Cationic regions

- Anionic framework
 - Center for electron transport
Electron crystal
- Cations
 - Site for dopants - control carrier conc.
 - Provide opportunity for disorder
 - Packing Arrangement complicated for large cell
Phonon Glass



Ternary A-Zn-Sb



Many A-Zn-Sb phases considered

Typically p-type

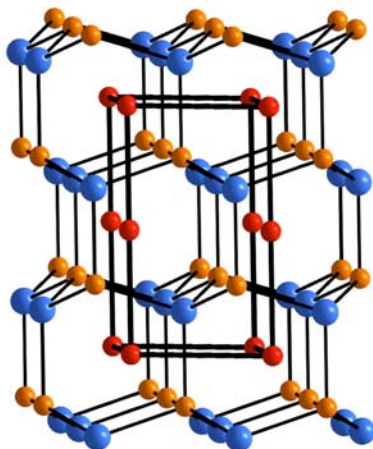
Sensitivity to air increases with

reactivity of A

content of A

LiZnSb

Predicted high zT
for n-type



Compound	Seebeck (300K)
CaZn_2Sb_2	+120
SrZn_2Sb_2	+125
BaZn_2Sb_2	+125
YbZn_2Sb_2	+48
EuZn_2Sb_2	+120
SrZnSb_2	+30
LiZnSb	+50
KZnSb	? too reactive
$\text{Ca}_9\text{Zn}_{4.5}\text{Sb}_9$	?
$\text{Yb}_{14}\text{ZnSb}_{11}$	+30

Toberer *Dalton Trans*, in press (2009)

Gascoin, *Adv. Funct. Mat.* **15**, 1860 (2005)

Wang, *APL*, **90**, 232107 (2007)

Toberer *JAP*, **105**, 063701, (2009)

May *JAP*, **106**, 013706, (2009)



$A^{+2}Zn_2Sb_2$



$A^{+2}Zn_2Sb_2$ Phases

Same nominal electron count

- Sr^{+2} , Ca^{+2} , Yb^{+2} , Eu^{+2}

Metallic to Semiconducting

High Thermopower

Promising thermoelectrics

- Peak zT 0.5 to ~ 1 (Eu, Yb-Cd)

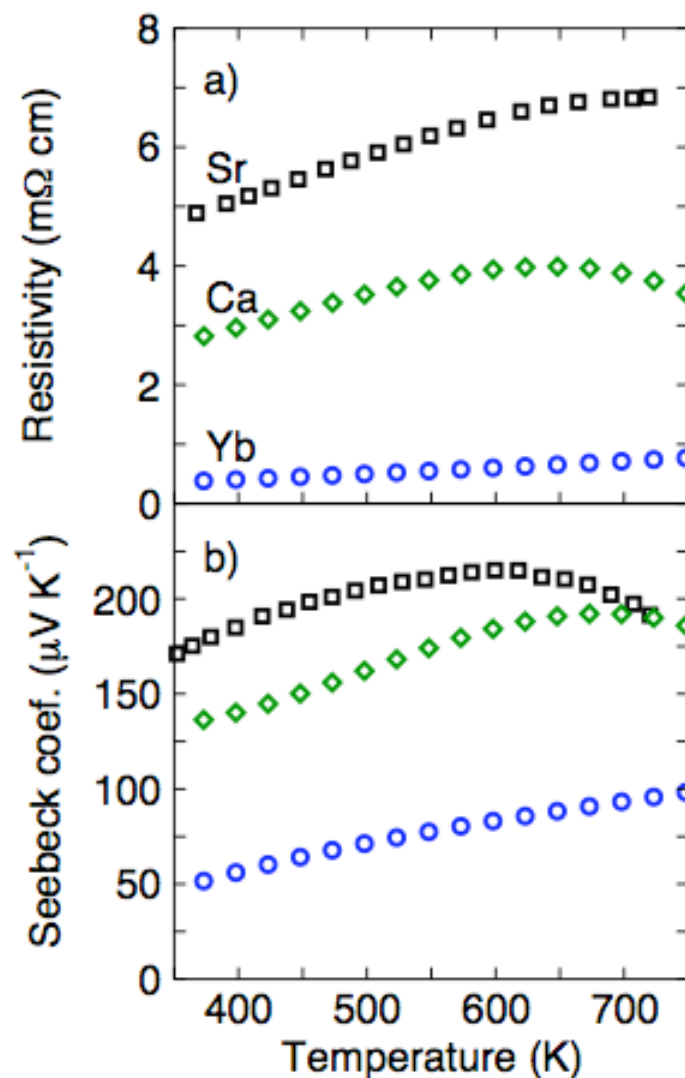
Why are properties different ?

Band Gap

Band Structure (effective mass)

Mobility

Carrier Concentration



Gascoin et. al. *Adv. Funct. Mat.*, **15**, p. 1860, (2005)

$A^{+2}Zn_2Sb_2$ Band Structure



$A^{+2}Zn_2Sb_2$ DFT calculations

Valence band (holes)

- mostly Sb character
- similar effective mass

Similar band gap

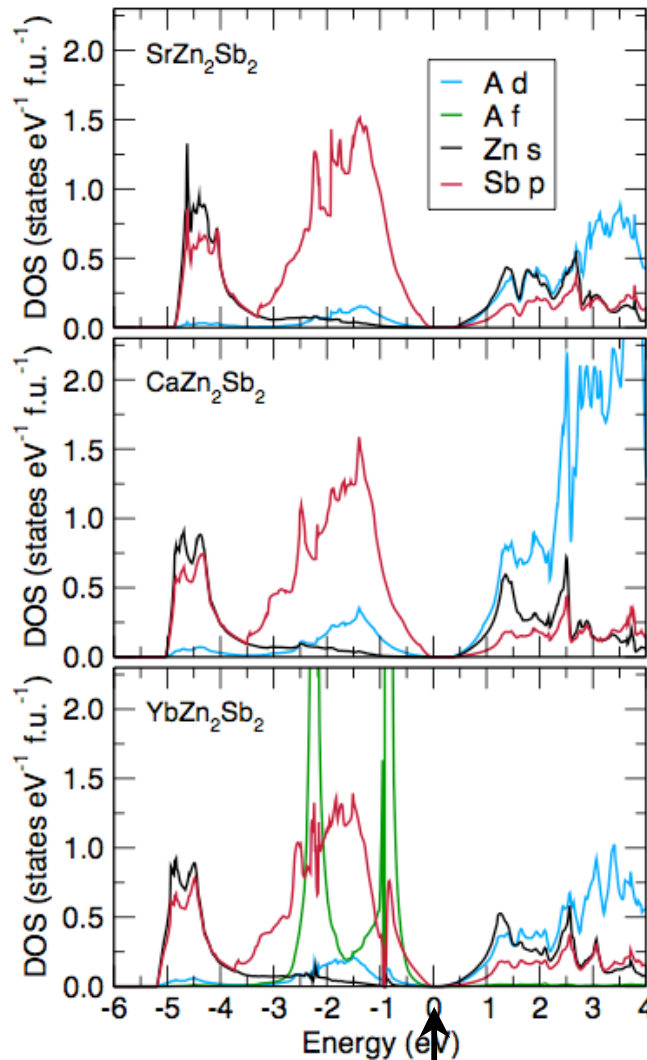
- Ca, Sr

Predict similar transport

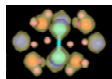
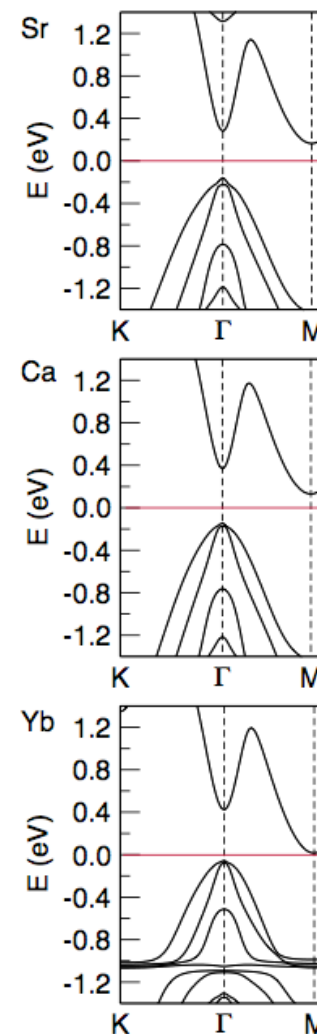
- A^{+2} influences conduction band (e^-)

Fermi Level at valence band edge

- No intrinsic holes (0K)
- A^{+2} does not change total number of valence states



Fermi Level



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$A^{+2}Zn_2Sb_2$ Carrier Concentration



Transport properties of $A^{+2}Zn_2Sb_2$

Trend with Carrier Concentration

- Carrier (hole) conc. from n_H

Seebeck Coefficient

$$\alpha = \frac{8\pi^2 k_B^2}{3eh^2} m^* T \left(\frac{\pi}{3n} \right)^{2/3}$$

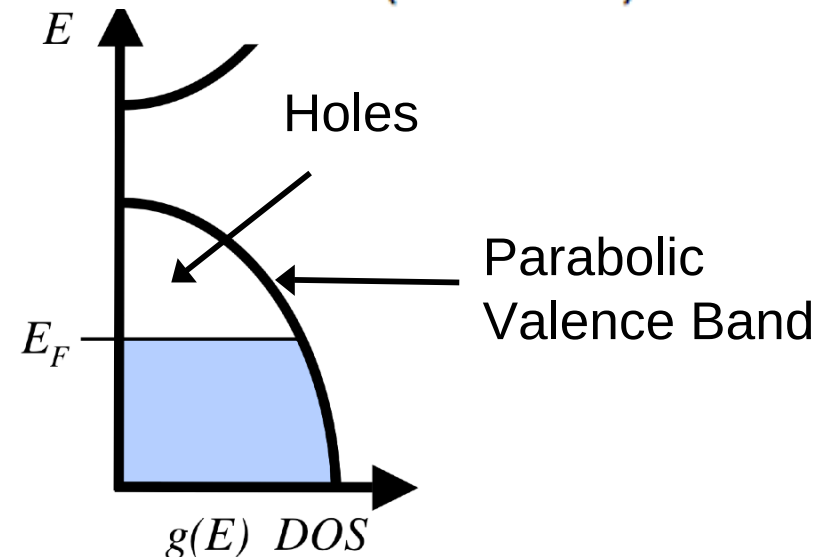
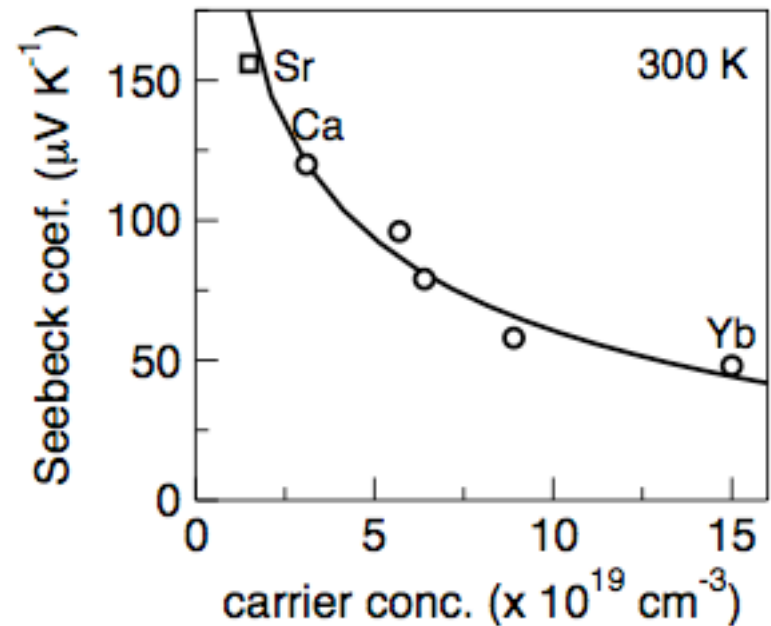
For common band approx

Parabolic bands

- constant effective mass $m^* = 0.6 m_e$
- Itinerant conductors
 - degenerate eq. shown above
- Band Gap $E_g = 0.3$ eV

Toberer, *Dalton Trans.* in press (2009)

Gascoin et. al. *Adv. Funct. Mat.*, **15**, p. 1860, (2005)



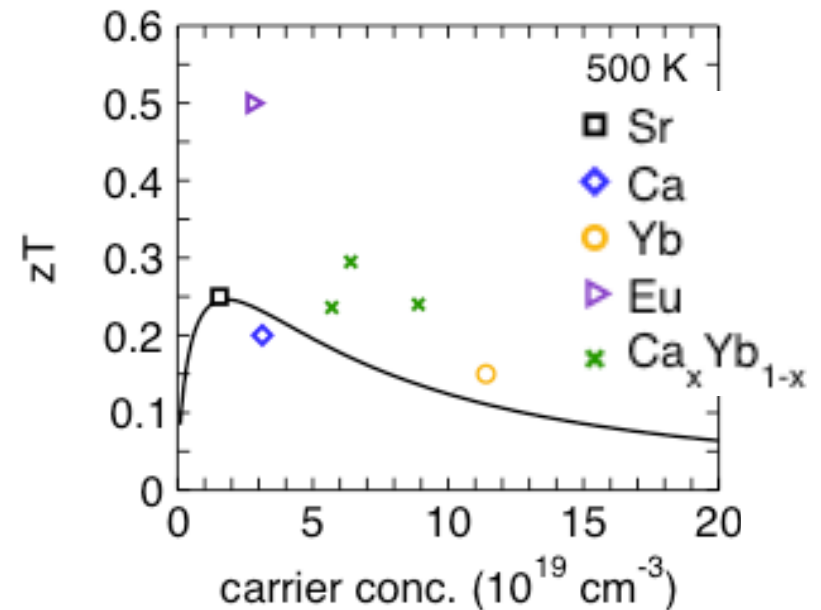
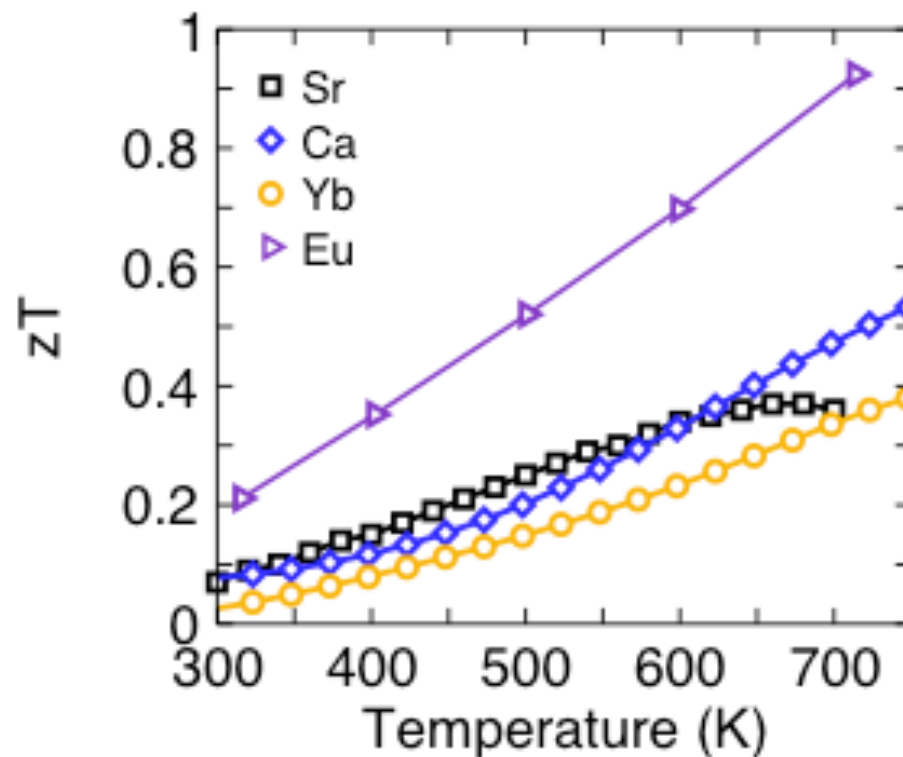
$A^{+2}Zn_2Sb_2$ zT



Tuning n changes transport properties; Sr, Ca, Eu near peak zT

Eu Zn_2Sb_2 high $zT \sim 1$. (due to mobility)

Lattice thermal conductivity should be reduced for higher zT



Mass contrast

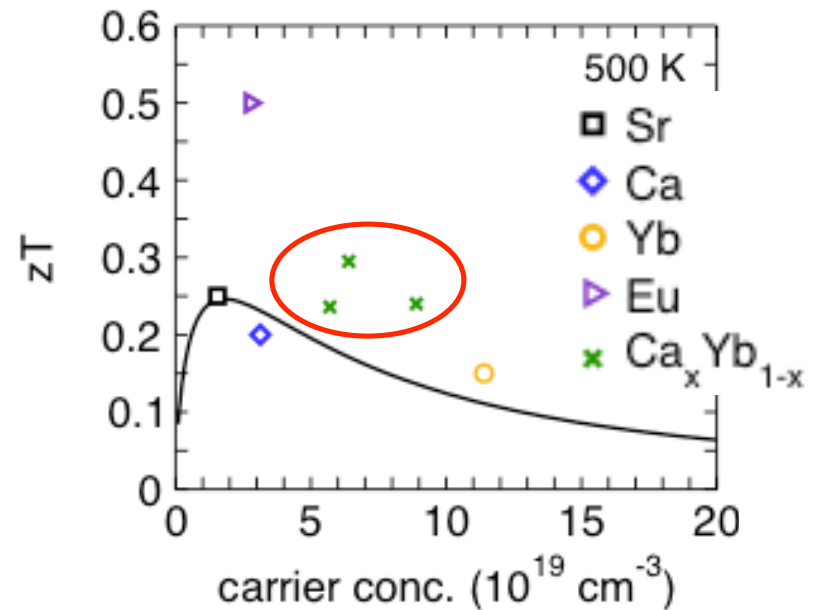
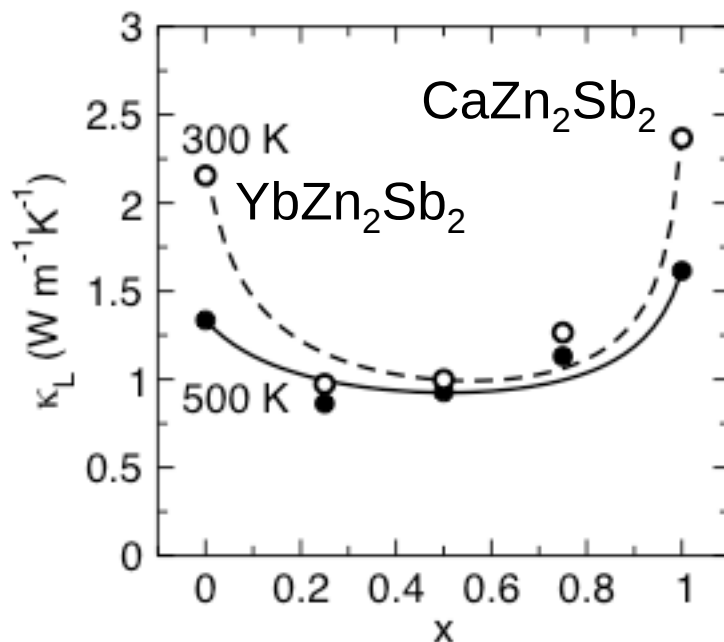
Mass contrast to lower the lattice thermal conductivity.

Example: $\text{Ca}_x\text{Yb}_{1-x}\text{Zn}_2\text{Sb}_2$ isoelectronic solid solution

Curves predicted from mass contrast and end member properties

$(\kappa_L, \theta_D, \nu)$

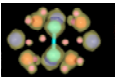
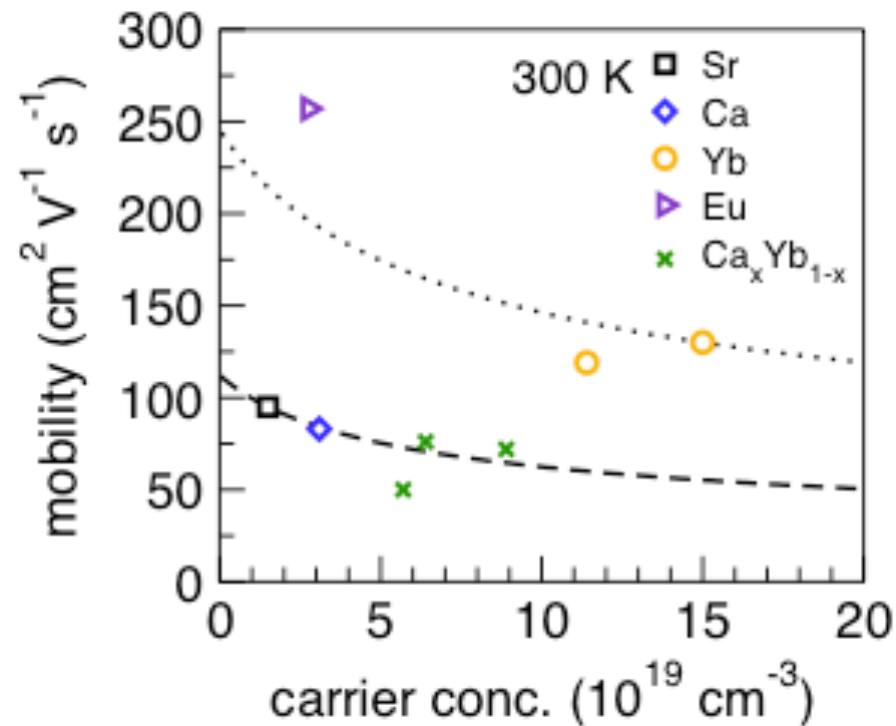
At high T, acoustic phonon scattering reduces effect



Mobility

Despite constant m^* , intrinsic mobility significantly higher for $A = \text{Eu}, \text{Yb}$

- Rare earth f levels - Yb, Eu
 - new mechanism for enhanced mobility?
- microstructure ? - grain boundaries, alignment

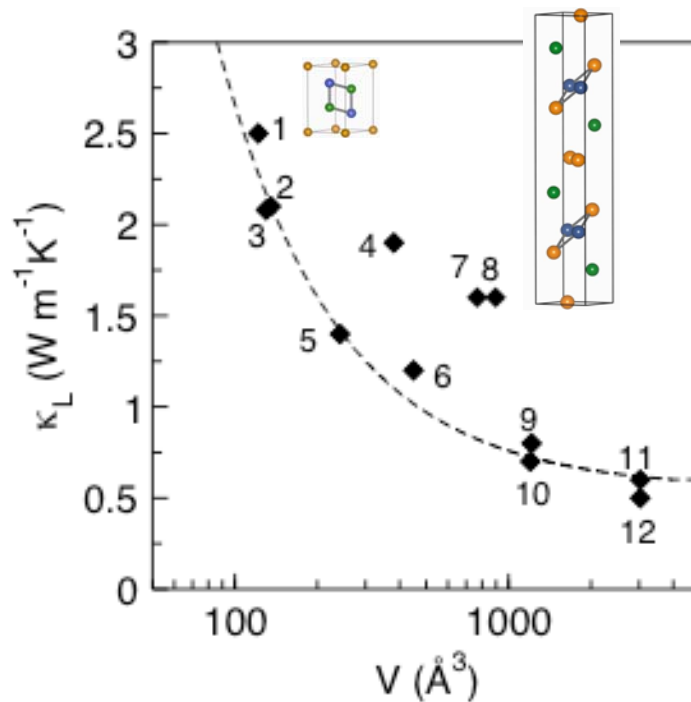


Cell Volume Trend in κ -lattice

Where to look for new high zT compounds?

- unit cell volume (V)

Primitive unit cell volume (V)
good indicator for
lattice thermal conductivity



$$\kappa_{lattice} = \frac{1}{3} C v l$$

C - heat capacity

v - speed of sound

l - phonon mean free path

If only acoustic modes contribute:

3 acoustic modes out of $3N$ in cell

V = Cell Volume

$$C_{ac} = 3k_B/V$$

$$\kappa_l = v l k_B / V$$

Dashed line: $V^{-1} + \kappa_{min}$

- | | |
|--|--|
| 1 - LiZnSb | 7 - Yb ₅ In ₂ Sb ₆ |
| 2 - SrZn ₂ Sb ₂ | 8 - Ba ₄ In ₈ Sb ₁₆ |
| 3 - Mg ₃ Sb ₂ | 9 - Yb ₁₁ Sb ₁₀ |
| 4 - CeFe ₄ Sb ₁₂ | 10 - Yb ₁₁ GaSb ₉ |
| 5 - BaZn ₂ Sb ₂ | 11 - Yb ₁₄ AlSb ₁₁ |
| 6 - SrZnSb ₂ | 12 - Yb ₁₄ MnSb ₁₁ |

SrZnSb₂ thermal transport



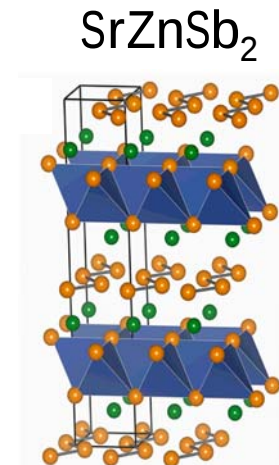
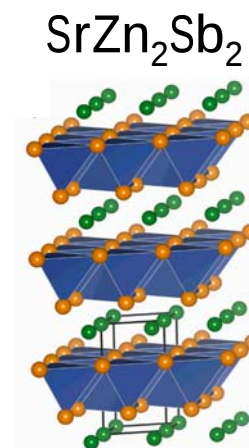
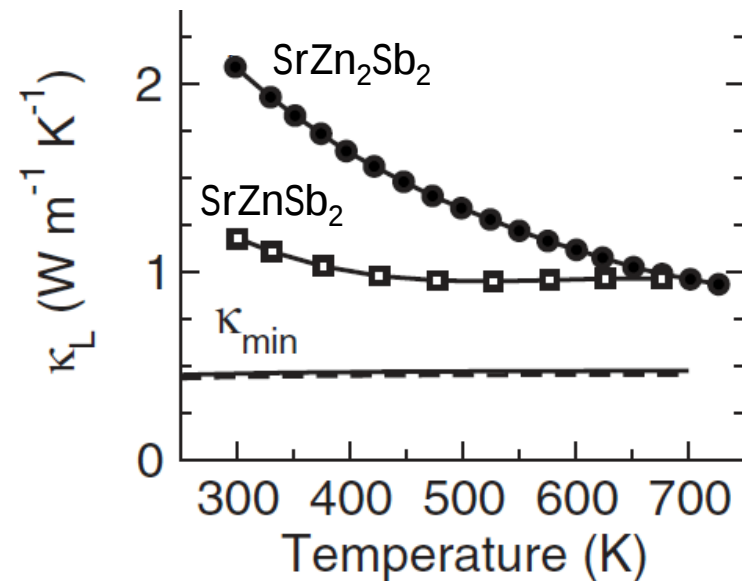
Similar bonding

- layers of covalently bound Zn-Sb
- Sr cationic layers

leads to similar speed of sound:

- SrZnSb₂ - 2040 m/s
- SrZn₂Sb₂ - 2010 m/s

More complex SrZnSb₂
displays significantly lower κ_L



May, *J. Applied Phys.*, **106**, 013706, (2009)

Summary



Zn-Sb phases

low cost
non-toxic
good zT

Zn_4Sb_3

Promising for power generation
need to understand

structure-property relationship

stability (thermal, chemical, gradient)

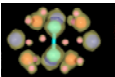
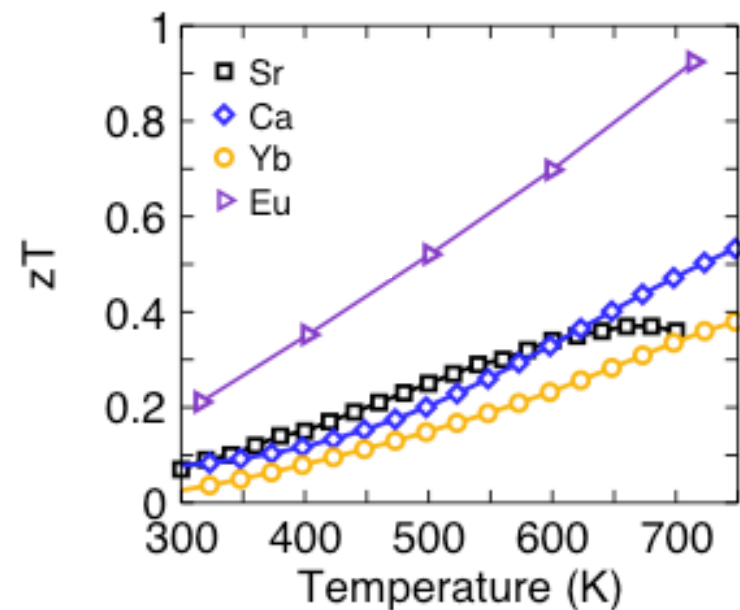
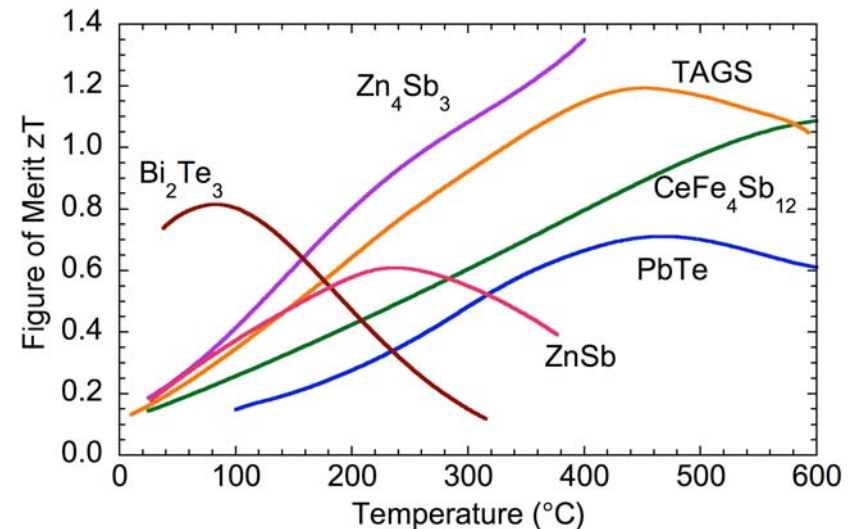
$\text{A}^{+2}\text{Zn}_2\text{Sb}_2$

good example of Zn-Sb derivative

High mobility, high zT In Rare Earth?

- new mechanism for high zT?
- EuZn_2Sb_2

other complex Zn-Sb derivatives ?



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Acknowledgements



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Andrew May

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